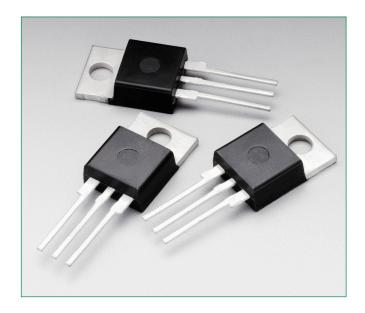
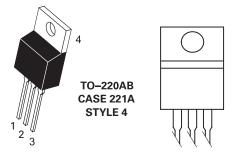
MAC16DG, MAC16MG, MAC16NG





Pin Out



Description

Designed for high performance full—wave ac control applications where high noise immunity and high commutating di/dt are required.

Features

- Blocking Voltage to 800 Volts
- On-State Current Rating of 16 Amperes RMS at 80°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dv/dt 500 V/µs minimum at 125°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220 Package
- High Commutating di/dt 9.0 A/ms minimum at 125°C
- These Devices are Pb-Free and are RoHS Compliant

Functional Diagram



Additional Information









Maximum Ratings $(T_J = 25^{\circ}C \text{ unless otherwise noted})$

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (- 40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open) MAC16D MAC16M MAC16N	V _{DRM} , V _{RRM}	400 600 800	V
On-State RMS Current (Full Cycle Sine Wave, 50 to 60 Hz, $T_c = 80$ °C)	I _{T (RMS)}	16	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_{\rm J}$ = 125°C)	I _{TSM}	150	А
Circuit Fusing Consideration (t = 8.3 ms)	l²t	93	A²sec
Peak Gate Power $(T_C = +80^{\circ}C, \text{ Pulse Width} = 1.0 \ \mu\text{s})$	$P_{\sf GM}$	20	W
Average Gate Power (t = 8.3 ms , $T_C = 80^{\circ}\text{C}$)	P _{G (AV)}	0.5	W
Operating Junction Temperature Range	T_{J}	-40 to +125	°C
Storage Temperature Range	T_{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance,	Junction-to-Case (AC) Junction-to-Ambient	R _{8JC}	2.0 62.5	°C/W
Maximum Lead Temperature for Solderi 10 seconds	ng Purposes, 1/8" from case for	T _L	260	°C

^{1.} V_{DBM} and V_{RBM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thyristors

Electrical Characteristics - OFF $(T_j = 25^{\circ}\text{C unless otherwise noted})$; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current	T _J = 25°C	l _{DRM} ,	-	-	0.01	μΑ
$(V_D = V_{DRM} = V_{RRM}; Gate Open)$	T _J = 125°C	I _{RRM}	-	-	2.0	mA

Electrical Characteristics - ON (T_J = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic			Min	Тур	Max	Unit
Peak On-State Voltage (Note 2) (I _{TM} = ±21 A Peak)		V _{TM}	-	1.2	1.6	V
Gate Trigger Current	MT2(+), G(+)		10	16	50	
(Continuous dc)	MT2(+), G(-)	I _{GT}	10	18	50	mA
$(V_D = 12 \text{ V}, \text{ R}_L = 100 \Omega)$	MT2(-), G(-)		10	22	50	
Gate Trigger Voltage (Continuous dc) $(V_D = 12 \text{ V}, R_L = 100 \Omega)$	MT2(+), G(+)		0.5	0.75	1.5	
	MT2(+), G(-)	V _{GT}	0.5	0.72	1.5	V
	MT2(-), G(-)		0.5	0.82	1.5	
Latching Current	MT2(+), G(+)		-	33	50	
$(V_D = 24 \text{ V, I}_G = 35 \text{ mA})$	MT2(+), G(-)	I _L	-	36	80	mA
	MT2(-), G(-)		-	33	50	
Holding Current ($V_D = 12 V_{dc}$, Gate Open, Initiating Current = ±150 mA))		I _H	-	20	50	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Dynamic Characteristics

Characteristic		Min	Тур	Max	Unit
Rate of Change of Commutating Current, See Figure 10. (VD = 400 V, ITM = 6.0 A, Commutating dv/dt = 24 V/ μ s, Gate Open, TJ = 125 °C, f = 250 Hz, No Snubber)	(di/dt)c	9.0	-	-	A/ms
Critical Rate of Rise of Off-State Voltage $(V_D = Rated\ V_{DRM},\ Exponential\ Waveform,\ Gate\ Open,\ T_J = 125^{\circ}C)$	dv/dt	600	-	_	V/µs

^{2.} Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle $\leq 2\%$.

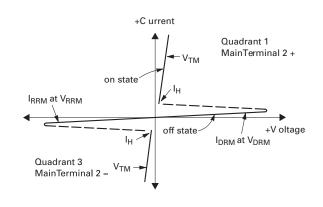


Surface Mount – 400V - 800V > MAC16 Series

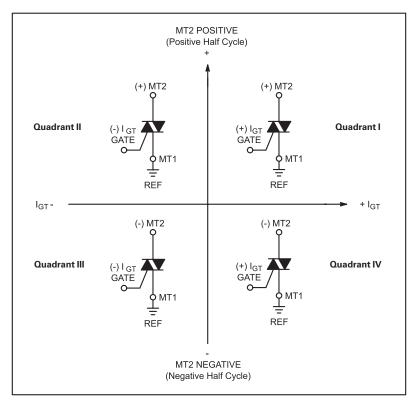
Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
$V_{_{\mathrm{RRM}}}$	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current

Thyristors



Quadrant Definitions for a Triac

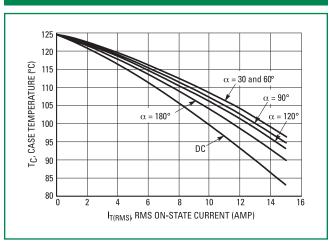


All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.



Figure 1. RMS Current Derating



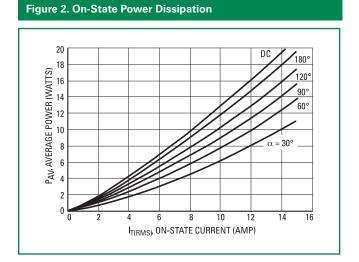


Figure 3. On-State Characteristics

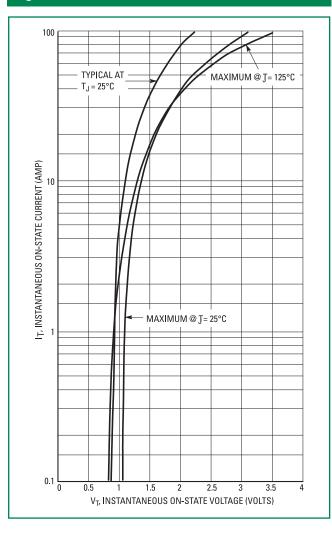


Figure 4. Thermal Response

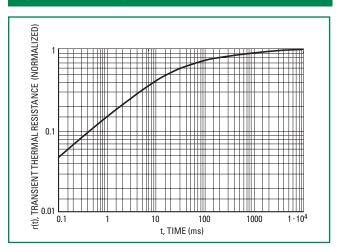
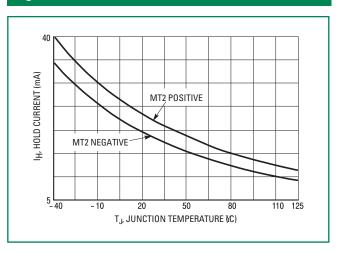


Figure 5. Hold Current Variation







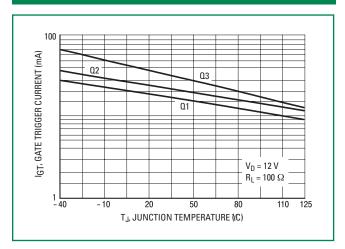


Figure 7. Gate Trigger Voltage vs Junction Temperature

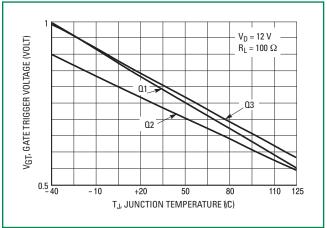


Figure 8. Critical Rate of Rise of Off–State Voltage (Exponential)

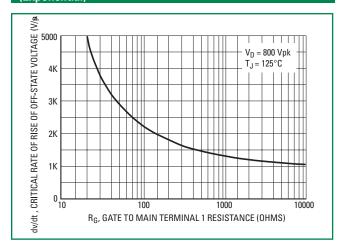


Figure 9. Critical Rate of Rise of Commutating Voltage

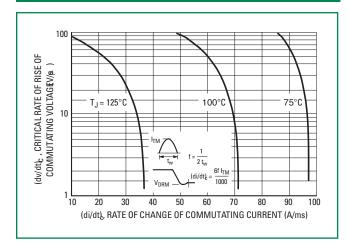
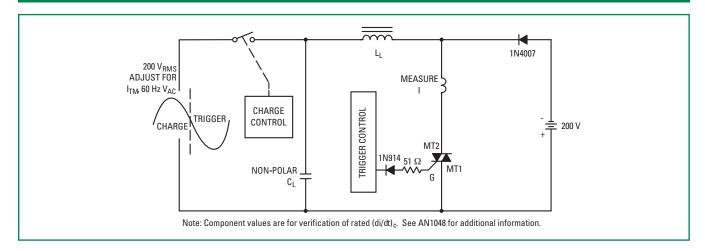
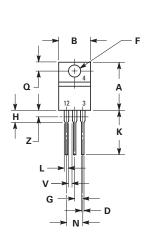
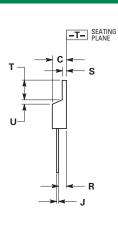


Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)c



Dimensions





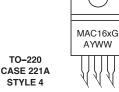
<u> </u>	Inches		Millim	neters	
Dim	Min	Max	Min	Max	
А	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.014	0.022	0.36	0.55	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
V	0.045		1.15		
Z		0.080		2.04	

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

Part Marking System



A=



D, M, or N
Assembly Location

Y= Year WW = Work Week <math>G = Pb-Free Package

Pin Assignment					
1	Main Terminal 1				
2	Main Terminal 2				
3	Gate				
4	Main Terminal 2				

Ordering Information

Device	Package	Shipping
MAC16DG		
MAC16MG	TO-220 (Pb-Free)	50 Units/ Rail
MAC16NG		

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